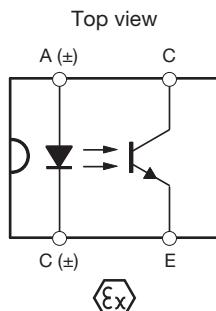
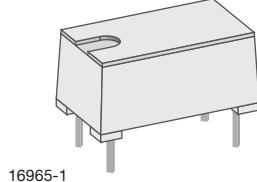


Optocoupler, Phototransistor Output, ATEX Certified



DESCRIPTION

The CNY65Exi consists of a phototransistor optically coupled to an infrared-emitting diode in a 4 pin plastic package. The components are mounted opposite one another, with a distance between input and output of > 3.0 mm; meeting the highest of safety requirements.

The CNY65Exi is ATEX certified for explosive atmospheres according to the European Guide line 94/9/EG.

AGENCY APPROVALS

- ATEX :PTB 03 ATEX 2033 U
- EN 60079-0 : 2012 + A11 : 2013
- EN 60079-11 : 2012
- EN 60079-26 : 2015

FEATURES

- ATEX certificate: PTB 03 ATEX 2033 U www.vishay.com/doc?85361
- Suitable for intrinsic safe circuits for gas and dust
- Gas safety provision: II (1) G [Ex ia] IIC
- Dust safety provision: II (1) D [Ex ia] IIIC
- Conforms to EN 60079-0: 2012 + A11: 2013
- Qualified for continuously, longterm, or frequently dangerous explosive environments, zone 0
- Isolation voltage (V_{ISO}) of 11 600 V_{peak} for 1 minute
- Distance from emitter to detector through insulation ≥ 3 mm
- CTR from 50 % to 300 %
- Very low coupling capacity (C_K)
 - 0.3 pF superior noise immunity between input and output pins
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

APPLICATIONS

- Electronics used in potentially explosive gas and dust environments
 - Safety related process automation and instrumentation
 - Natural gas metering and flow measurement
 - Power and motor switching
 - Power supplies, metering, and data acquisition
 - Lighting and signaling
 - Petrol and grain transport and storage

ORDERING INFORMATION									
PART NUMBER					PACKAGE OPTION				
C N Y 6 5 X					E x i				
CTR BIN					PACKAGE OPTION				
DIP-4					15.24 mm				
AGENCY CERTIFIED/PACKAGE		CTR (%)							
ATEX		50 to 300				100 to 200			
DIP-4, HV, high isolation distance		CNY65Exi				CNY65BExi			

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25^{\circ}C$, unless otherwise specified)				
PARAMETER	CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	5	V
Forward current		I_F	75	mA
Forward surge current	$t_p \leq 10 \mu s$	I_{FSM}	1.5	A
Power dissipation		P_{diss}	120	mW
Junction temperature		T_j	100	$^{\circ}C$
OUTPUT				
Collector emitter voltage		V_{CEO}	32	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Collector peak current	$t_p/T = 0.5, t_p \leq 10 \text{ ms}$	I_{CM}	100	mA
Power dissipation		P_{diss}	130	mW
Junction temperature		T_j	100	$^{\circ}C$
COUPLER				
Total power dissipation		P_{tot}	250	mW
Ambient temperature range		T_{amb}	-55 to +85	$^{\circ}C$
Storage temperature range		T_{stg}	-55 to +100	$^{\circ}C$
Soldering temperature	2 mm from case, $t \leq 10 \text{ s}$	T_{sld}	260	$^{\circ}C$

Note

- Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}C$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = 50 \text{ mA}$	V_F	-	1.25	1.6	V
OUTPUT						
Collector emitter voltage	$I_C = 1 \text{ mA}$	V_{CEO}	32	-	-	V
Emitter collector voltage	$I_E = 100 \mu A$	V_{ECO}	7	-	-	V
Collector dark current	$V_{CE} = 20 \text{ V}, I_f = 0, E = 0$	I_{CEO}	-	-	200	nA
COUPLER						
Isolation resistance	$V_{IO} = 1 \text{ kV}, 40\% \text{ relative humidity}$	$R_{IO}^{(1)}$	-	10^{12}	-	Ω
Collector saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V_{CESat}	-	-	0.3	V
Cut-off frequency	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 100 \Omega$	f_c	110	-	-	kHz
Coupling capacitance	$f = 1 \text{ MHz}$	C_k	-	0.3	-	pF

Notes

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements

⁽¹⁾ Related to standard climate 23/50 DIN 50014

CURRENT TRANSFER RATIO ($T_{amb} = 25^{\circ}C$, unless otherwise specified)						
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.
I_C/I_F	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$	CNY65Exi	CTR	50	100	300
		CNY65BExi	CTR	100	-	200

SAFETY AND INSULATION RATINGS			
PARAMETER	SYMBOL	VALUE	UNIT
MAXIMUM SAFETY RATINGS			
Output safety power	P _{SO}	250	mW
Input safety current	I _{si}	120	mW
Safety temperature	T _S	150	°C
Comparative tracking index	CTI	475	
INSULATION RATED PARAMETERS			
Maximum withstanding isolation voltage	V _{ISO}	8200	V _{RMS}
Maximum transient isolation voltage	V _{IOTM}	12 000	V _{peak}
Maximum repetitive peak isolation voltage	V _{IORM}	1450	V _{peak}
Insulation resistance	R _{IO}	$\geq 10^{12}$	Ω
Isolation resistance	R _{IO}	$\geq 10^{11}$	Ω
Climatic classification (according to IEC 68 part 1)		40 / 110 / 21	
Environment (pollution degree in accordance to DIN VDE 0109)		2	
Creepage		≥ 14	mm
Insulation thickness	DTI	3	mm

Note

- According to DIN EN 60747-5-5 (see Fig. 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	V _S = 5 V, I _C = 5 mA, R _L = 100 Ω, (see Fig. 1)	t _d	-	2.6	-	μs
Rise time	V _S = 5 V, I _C = 5 mA, R _L = 100 Ω, (see Fig. 1)	t _r	-	2.4	-	μs
Fall time	V _S = 5 V, I _C = 5 mA, R _L = 100 Ω, (see Fig. 1)	t _f	-	2.4	-	μs
Storage time	V _S = 5 V, I _C = 5 mA, R _L = 100 Ω, (see Fig. 1)	t _s	-	0.3	-	μs
Turn-on time	V _S = 5 V, I _C = 5 mA, R _L = 100 Ω, (see Fig. 1)	t _{on}	-	5	-	μs
Turn-off time	V _S = 5 V, I _C = 5 mA, R _L = 100 Ω, (see Fig. 1)	t _{off}	-	3	-	μs
Turn-on time	V _S = 5 V, I _F = 10 mA, R _L = 1 kΩ, (see Fig. 2)	t _{on}	-	25	-	μs
Turn-off time	V _S = 5 V, I _F = 10 mA, R _L = 1 kΩ, (see Fig. 2)	t _{off}	-	42.5	-	μs

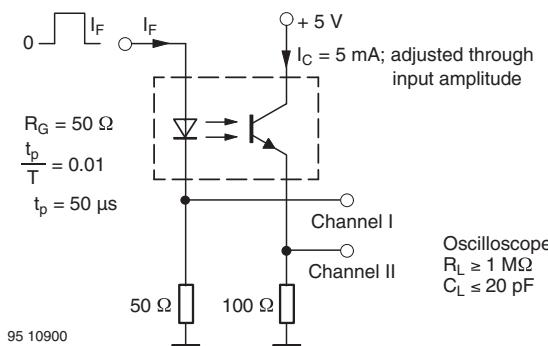


Fig. 1 - Test Circuit, Non-Saturated Operation

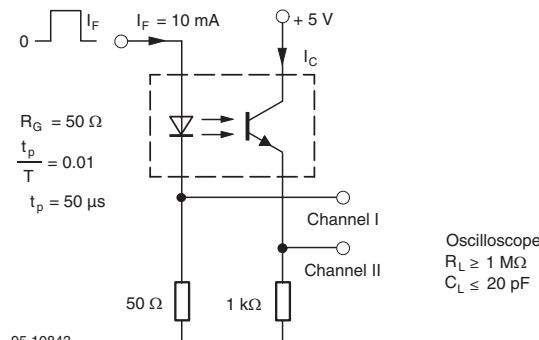


Fig. 2 - Test Circuit, Saturated Operation

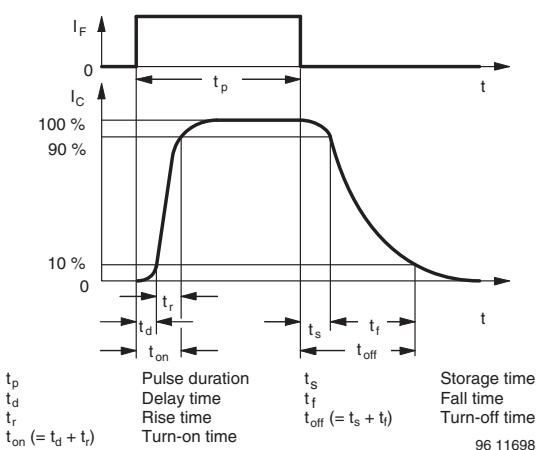


Fig. 3 - Switching Times

TYPICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified)

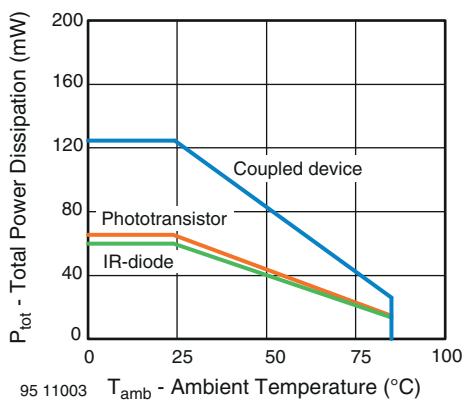


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

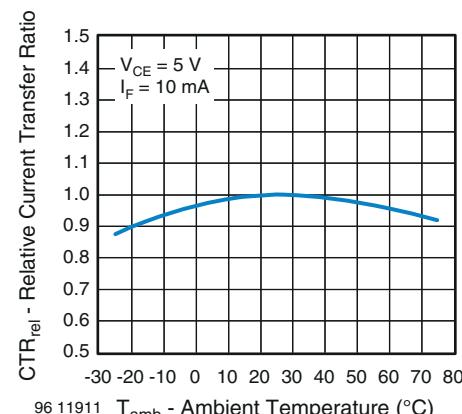


Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature

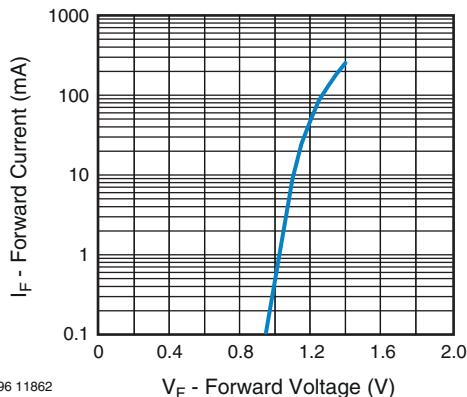


Fig. 5 - Forward Current vs. Forward Voltage

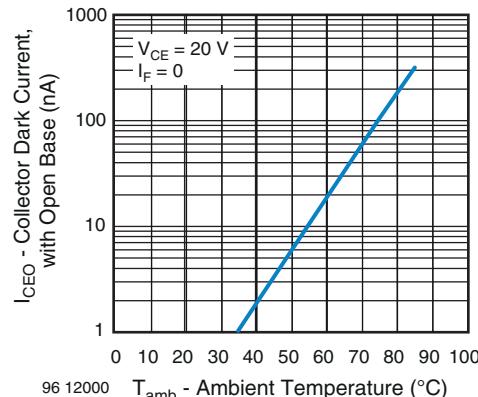


Fig. 7 - Collector Dark Current vs. Ambient Temperature

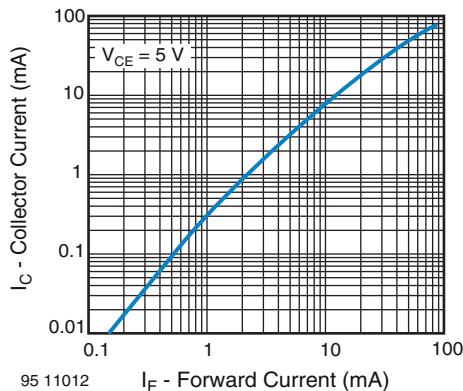


Fig. 8 - Collector Current vs. Forward Current

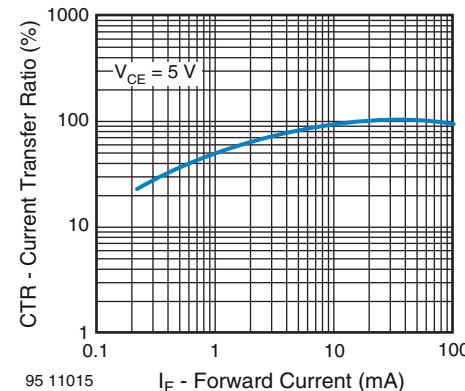


Fig. 11 - Current Transfer Ratio vs. Forward Current

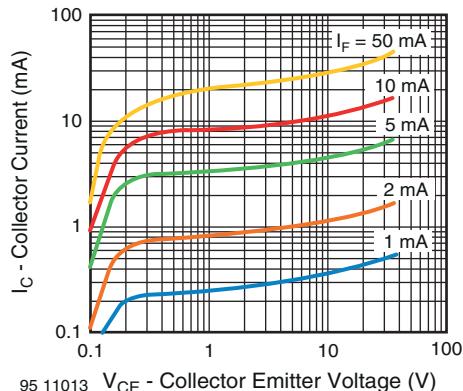


Fig. 9 - Collector Current vs. Collector Emitter Voltage

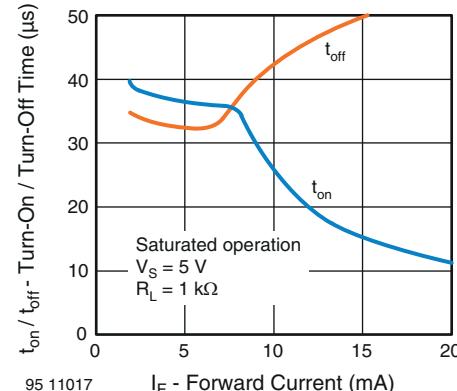


Fig. 12 - Turn-On / Turn-Off Time vs. Forward Current

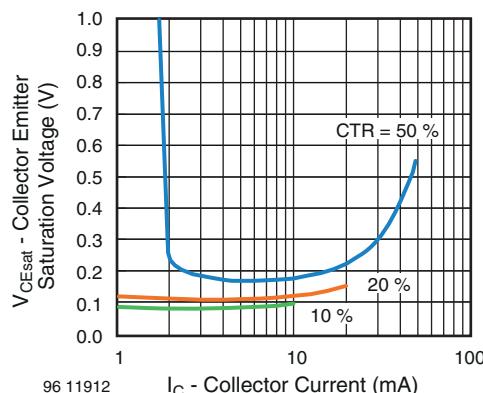


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

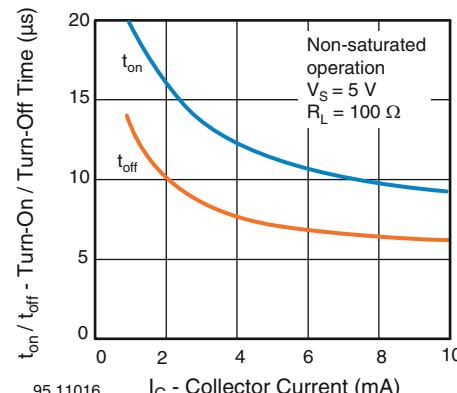
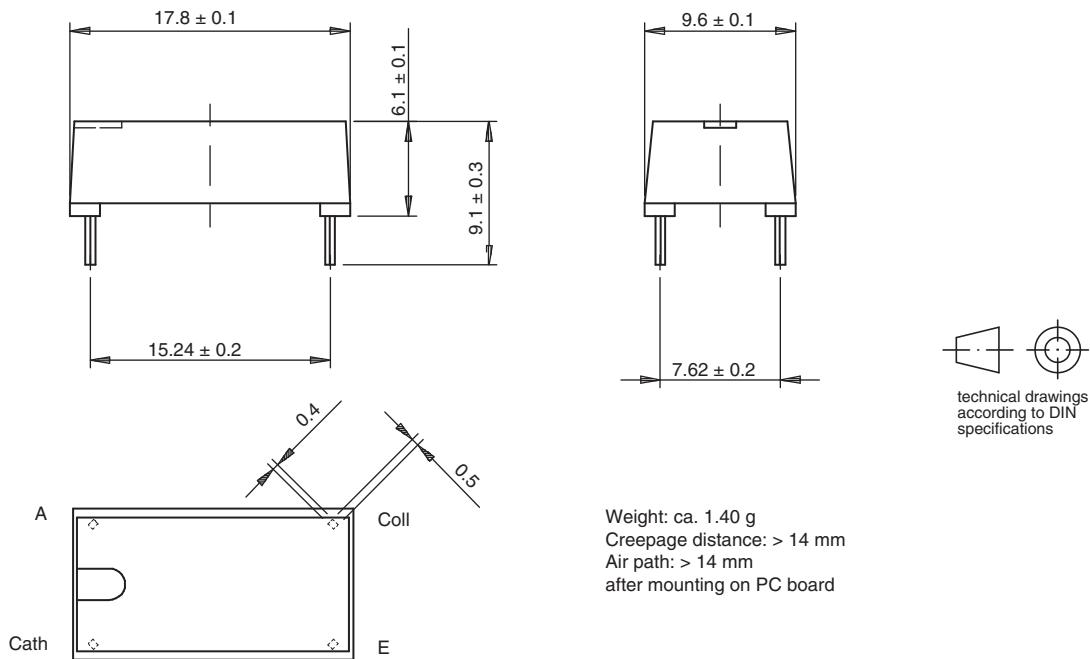


Fig. 13 - Turn-On / Turn-Off Time vs. Collector Current

PACKAGE DIMENSIONS (in millimeters)


Drawing-No.: 6.544-5036.01-1

Issue: 2; 10.11.98

14763

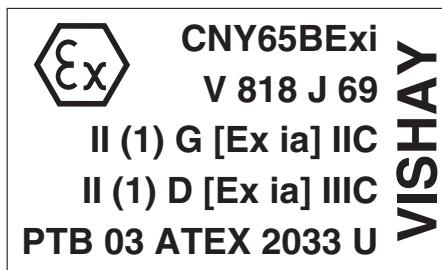
PACKAGE MARKING (example of CNY65BExi)


Fig. 14 - Top Marking

Theresienstrasse 2
74074 Heilbronn, Germany

Fig. 15 - Side Marking

TUBE INFORMATION			
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX
CNY65Exi	30	35	1050

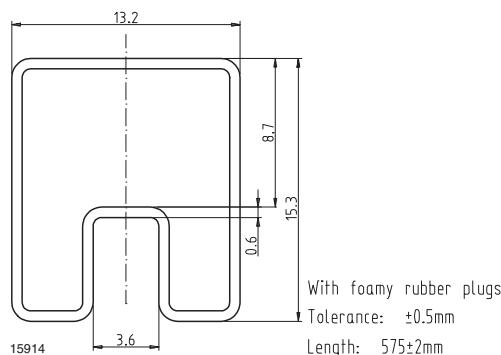


Fig. 16 - CNY65Exi

SOLDER PROFILES

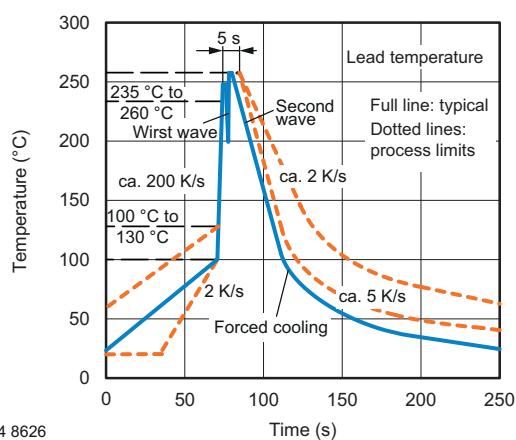


Fig. 17 - Wave Soldering Double Wave Profile According to J-STD-020 for Through-Hole Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2

Floor life: unlimited

Conditions: $T_{\text{amb}} < 30\text{ °C}$, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020

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